



SINGLE P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(ON)} max	I _D max T _A = +25°C
	11mΩ @ V _{GS} = -10V	-13A
-30V	17mΩ @ V _{GS} = -4.5V	-9.9A

Description

This MOSFET has been designed to minimize the on-state resistance ($R_{DS(on)}$) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- Backlighting
- Power Management Functions
- DC-DC Converters

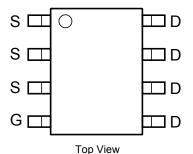
Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

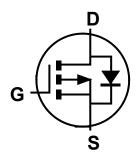
Mechanical Data

- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals Connections: See Diagram
- Terminals: Finish Matte Tin annealed over Copper lead frame. Solderable per MIL-STD-202, Method 208
- Weight: 0.074g (approximate)





Internal Schematic



Equivalent circuit

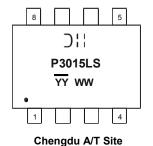
Ordering Information (Note 4)

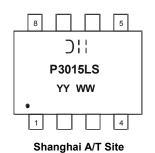
Ī	Part Number	Case	Packaging
	DMP3015LSS-13	SO-8	2500/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information





O!! = Manufacturer's Marking
P3015LS = Product Type Marking Code
YYWW = Date Code Marking
YY or YY = Year (ex: 13 = 2013)
WW = Week (01 - 53)

YY = Date Code Marking for SAT (Shanghai Assembly/ Test site)
YY = Date Code Marking for CAT (Chengdu Assembly/ Test site)



Characteristic			Symbol	Value	Units
Drain-Source Voltage			V_{DSS}	-30	V
Gate-Source Voltage			V_{GSS}	±20	V
Drain Current (Note 5)	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	I _D	-13 -9.75	А
Pulsed Drain Current (Note 6)			I _{DM}	-45	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	P _D	2.5	W
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	50	°C/W
Operating and Storage Temperature Range	T _{J,} T _{STG}	-55 to +150	°C

Notes: 5. Device mounted on 2 oz. Copper pads on FR-4 PCB with $R_{\theta JA}$ = 50°C/W.

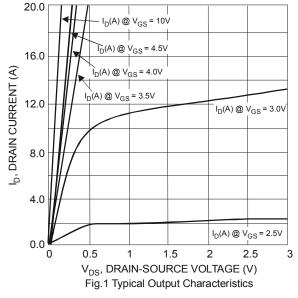
6. Pulse width ≤10µS, Duty Cycle ≤1%.

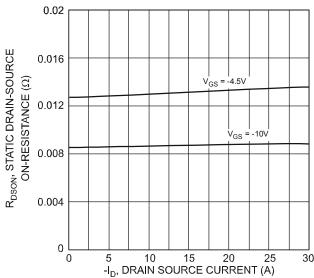
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

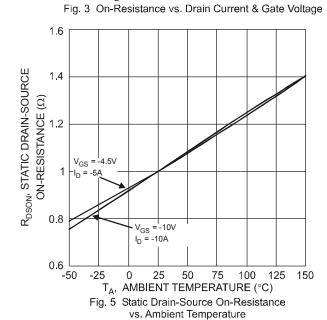
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-30			V	$V_{GS} = 0V$, $I_D = -250\mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	_	_	-1	μΑ	$V_{DS} = -30V, V_{GS} = 0V$	
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-1		-2	V	$V_{DS} = V_{GS}, I_D = -250 \mu A$	
Static Drain-Source On-Resistance	R _{DS (ON)}	_	9 14	11 17	mΩ	$V_{GS} = -10V, I_D = -13A$	
Forward Transconductance			15	_	S	$V_{GS} = -4.5V, I_D = -10A$	
	9fs				~	$V_{DS} = -15V, I_{D} = -8A$	
Diode Forward Voltage (Note 7)	V_{SD}	-0.5	_	-1.1	V	$V_{GS} = 0V, I_S = -2.1A$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	C _{iss}	_	2748		pF	., - 20,/ ,/ - 0,/	
Output Capacitance	Coss		357		pF	$V_{DS} = -20V, V_{GS} = 0V$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	_	356	1	pF	T = 1.0MHZ	
Gate Resistance	R_G	_	2.0		Ω	$V_{DS} = 0V$, $V_{GS} = 0V$ f = 1.0MHz	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	Qg	_	30.0 60.4	_	$V_{DS} = -10V, V_{GS} = -10V, I$	V_{DS} = -10V, V_{GS} = -4.5V, I_{D} = -13A V_{DS} = -10V, V_{GS} = -10V, I_{D} = -13A	
Gate-Source Charge	Q _{gs}	_	7.2	_		V _{DS} = -10V, V _{GS} = -10V, I _D = -13A	
Gate-Drain Charge	Q_{gd}	_	16.4	_		V _{DS} = -10V, V _{GS} = -10V, I _D = -13A	
Turn-On Delay Time	t _{d(on)}	_	11.2				
Rise Time	t _r	_	12.4		20	$V_{DS} = -15V$, $V_{GS} = -10V$,	
Turn-Off Delay Time	t _{d(off)}	_	104.9	_	ns	$I_D = -1A, R_G = 6.0\Omega$	
Fall Time	t _f	_	61.7				

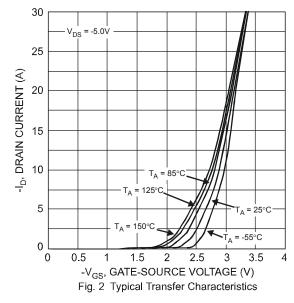
Notes: 7. Short duration pulse test used to minimize self-heating effect. 8. Guaranteed by design. Not subject to product testing.











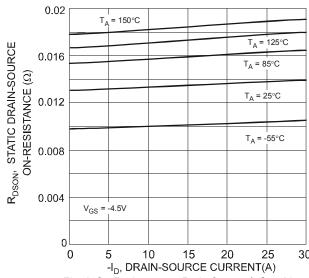
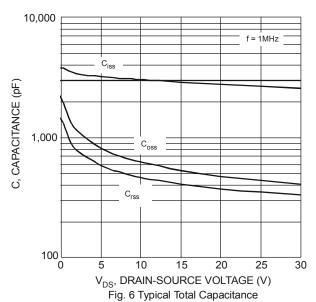


Fig. 4 On-Resistance vs.Drain Current & Gate Voltage





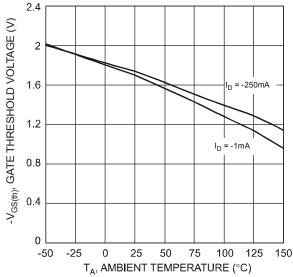


Fig. 7 Gate Threshold Variation vs. Ambient Temperature

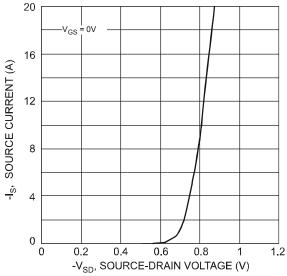
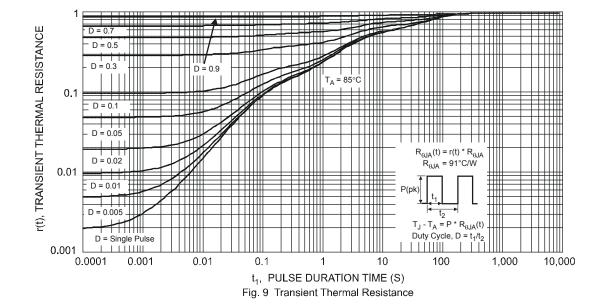
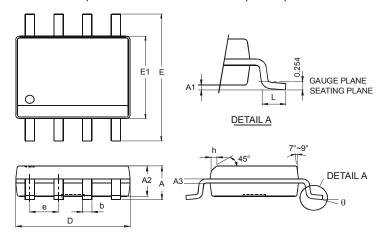


Fig. 8 Forward Drain Current vs. Source-Drain Voltage



Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



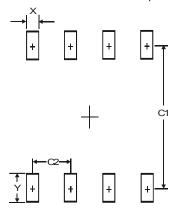
30-0					
Dim	Min	Max			
Α	_	1.75			
A 1	0.08	0.25			
A2	1.30	1.50			
А3	0.20	Тур.			
b	0.3	0.5			
D	4.80	5.30			
Е	5.79	6.20			
E1	3.70	4.10			
е	1.27 Typ.				
h		0.35			
٦	0.38	1.27			
θ	0°	8°			
All Dimensions in mm					
•					

SO_8



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

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